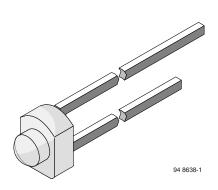
GREEN (5-2008)\*\*



### Vishay Semiconductors

### Silicon NPN Phototransistor

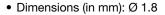


# DESCRIPTION

BPW17N is a silicon NPN phototransistor with high radiant sensitivity in clear, T-3/4 plastic package with lens. It is sensitive to visible and near infrared radiation. On PCB this package size enables assembly of arrays with 2.54 mm pitch.

#### **FEATURES**

Package type: leaded
Package form: T-¾



• High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

• Fast response times

• Angle of half sensitivity:  $\varphi = \pm 12^{\circ}$ 

 Comliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Note

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

#### **APPLICATIONS**

Detector in electronic control and drive circuits

PRODUCT SUMMARY			
COMPONENT	I <sub>ca</sub> (mA)	φ (deg)	λ <sub>0.1</sub> (nm)
BPW17N	1.0	± 12	450 to 1040

#### Note

• Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW17N	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-¾	

#### Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector emitter voltage		V <sub>CEO</sub>	32	V
Emitter collector voltage		V <sub>ECO</sub>	5	V
Collector current		I <sub>C</sub>	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Power dissipation	T <sub>amb</sub> ≤ 55 °C	P <sub>V</sub>	100	mW
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	t ≤ 3 s	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	450	K/W



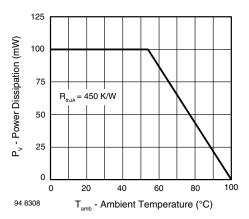
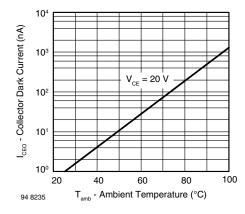
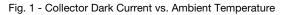


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	32			V
Collector emitter dark current	$V_{CE} = 20 \text{ V}, E = 0$	I <sub>CEO</sub>		1	200	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz, E = 0	C <sub>CEO</sub>		8		pF
Collector light current	$E_e$ = 1 mW/cm <sup>2</sup> , $\lambda$ = 950 nm, $V_{CE}$ = 5 V	I <sub>ca</sub>	0.5	1.0		mA
Angle of half sensitivity		φ		± 12		deg
Wavelength of peak sensitivity		$\lambda_{p}$		825		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		450 to 1040		nm
Collector emitter saturation voltage	$E_e$ = 1 mW/cm <sup>2</sup> , $\lambda$ = 950 nm, $I_C$ = 0.1 mA	V <sub>CEsat</sub>			0.3	V
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>on</sub>		4.8		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>off</sub>		5.0		μs
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f <sub>c</sub>		120		kHz

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)





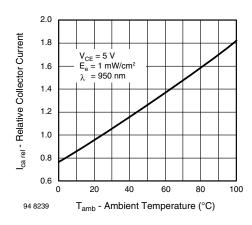


Fig. 2 - Relative Collector Current vs. Ambient Temperature

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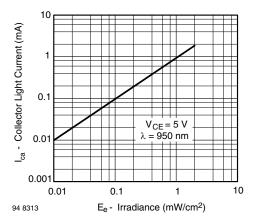


Fig. 3 - Collector Light Current vs. Irradiance

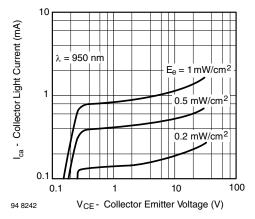


Fig. 4 - Collector Light Current vs. Collector Emitter Voltage

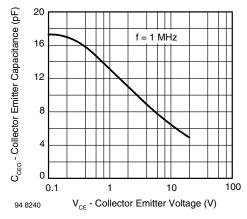


Fig. 5 - Collector Emitter Capacitance vs. Collector Emitter Voltage

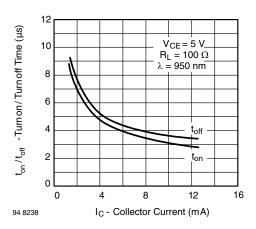


Fig. 6 - Turn-on/Turn-off Time vs. Collector Current

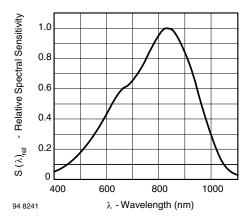


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

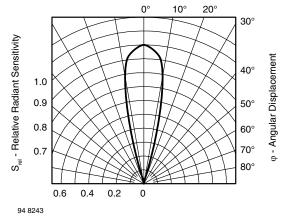
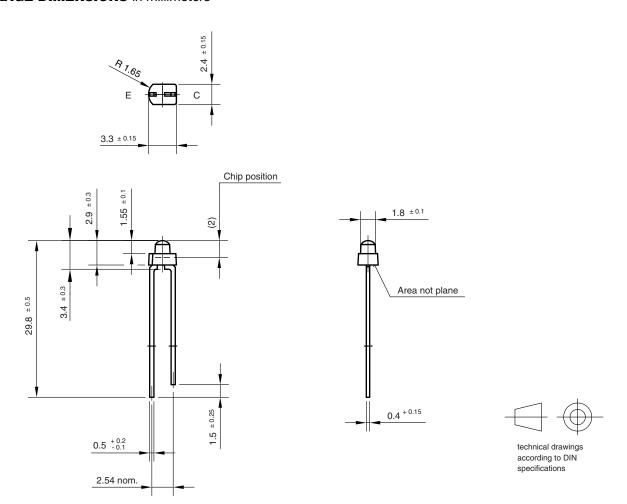


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement

# Vishay Semiconductors

### **PACKAGE DIMENSIONS** in millimeters



6.544-5042.01-4 Issue:1; 01.07.96 96 12187



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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